HD14522B, HD14526B

Programmable Divide-by-N 4-bit Counter

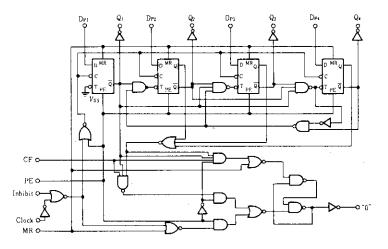
The HD14522B BCD counter and the HD14526B binary counter are programmable, cascadable down counters with a decoded "0" atate output for divide-by-N applications. In single stage applications the "0" output is applied to the Preset Enable input. The Cascade Feedback input allows cascade divide-by-N operation with no additional gates required. The Clock Inhibit input allows disabling low power dissipation and/or high noise immunity.

FEATURES

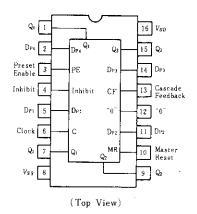
- Quiescent Current=5nA/pkg typ. @5V
- Supply Voltage Range=3 to 18V
- Internally Synchronous for High Internal and External Speeds
- Logic Edge-clocked Design . . . Incremented on Positive transi-
- tion of Clock or Negative Transition of Clock Inhibit
- 5MHz Counting Rate
- Asynchronous Preset Enable
- Capable of Driving One Low-power Schottky 1 TL Load Over the Rated Temperture Range

LOGIC DIAGRAM





PIN ARRANGEMENT



TRUTH TABLE

Both Types

Clock	Inhibit	Preset Enable	Master Reset	Action
0	0	0	0	No Count
	0	0	0	Count 1
×	1	0	0	No Count
1		0	0	Count 1
×	×	1	0	Preset
×	×	×	1	Reset

•HD14522B

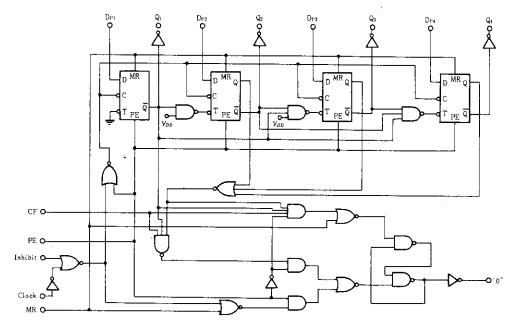
Count	Q.	Q3	Qz	\mathbf{Q}_1
9	1	0	0	1
8	1	0	0	0
7	0	1	1	1
6	0	1	1	0
5	0	1	0	1
4	0	1	Û	0
3	0	0	1	1
2	0	0	1	0
1	0	0	0	1
0	0	0	0	0

15	1	1	1	1
14	1	1	1	0
13	1	1	0	1
12	1	1	0	0
11	1	0	1	1
10	1	0	1	0

• HD14526B Count Q. Q. Q.

	•	•	۰ v	٠ .
11	1	0	1	1
10	1	0	1	0
9	1	0	0	1
8	1	0	0	0
7	0	1	1	1
6	0	1	1	0
5	0	1	0	1
4	0	1	0	0
3	0	-0	1	1
2	0	0	1	0
1	0	0	0	1
0	0	0	0	0

●HD14526B



ELECTRICAL CHARACTERISTICS

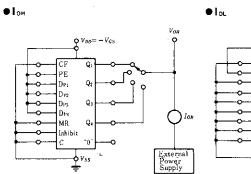
Characteristic	Symbol	Test Conditions		-4	10°C		25°C			85℃	
	Symbol	$V_{DD}(\mathbf{V})$	Test Conditions	min	max	min	typ	max	min	max	Unit
		5.0			0.05	—	0	0.05	_	0.05	v
	Vol	10	$V_{i} = V_{DD}$ or 0	-	0.05	_	0	0.05	_	0.05	
Output Voltage		15		-	0.05		0	0.05		0.05	
output voltage	-	5.0	$V_{in} = 0$ or V_{DD}	4.95	-	4.95	5.0	_	4.95	_	
	Von	10		9.95		9.95	10	-	9.95		l v
· · · · · · · · · · · · · · · · · · ·		15		14.95	-	14.95	15	_	14.95	—	
	-	5.0	$V_{evt} = 4.5 \text{ or } 0.5 \text{V}$	-	1.5	_	2.25	1.5	_	1.5	v
	VIL	10	V _{out} =9.0 or 1.0V		3.0		4.50	3.0	—	3.0	
Input Voltage		15	$V_{out} = 13.5 \text{ or } 1.5 \text{V}$		4.0		6.75	4.0	_	4.0	
	VIH	5.0	V _{out} =0.5 or 4.5V	3.5	-	3.5	2.75	-	3.5	—	v
		10	V _{est} =1.0 or 9.0V	7.0	-	7.0	5.50		7.0	-	
		15	$V_{ext} = 1.5$ or $13.5V$	11.0	-	11.0	8.25		11.0		
	Іон Іог	5.0	$V_{0H} = 2.5V$	-1.0		-0.8	-1.7		-0.6	-	mA
		5.0	Von-4.6V	-0.2	-	-0.16	-0.36	_	-0.12	—	
		10	$V_{OH} = 9.5 V$	-0.5		-0.4	-0.9	_	-0.3	-	
Output Drive Current		15	$V_{OB} = 13.5 V$	-1.4		-1.2	-3.5	_	-1.0		
		5.0	$V_{0L} = 0.4 V$	0.52	- 1	0.44	0.88	-	0.36	—	
		10	$V_{0L} = 0.5 V$	1.3	—	1.1	2.25	-	0.9		mA
		15	$V_{0L} = 1.5 V$	3.6	-	3.0	8.8	-	2.4		
Input Current	Iin	15			±0.3	_	± 0.00001	± 0.3	—	±1.0	μA
Input Capacitance	Cin		$V_{in}=0$	-	—	_	5.0	7.5	—	-	pF
Quiescent Current		5.0	Zero Signal,		20	—	0.005	20	—	150	-
	Ιου	10	0	-	40		0.010	40		300	μA
		15	per Package		80		0.015	80	-	600	
		5.0	Dynamic $+I_{DD}$,	_		_	1.7	—	-		
Total Supply Current*	Ιτ	10	per Gate	-	_	—	3.4	-	—	-	μA
		15	$C_{\perp} = 50 \text{ pF}, f = 1 \text{ kHz}$	_	-		5,1		-		

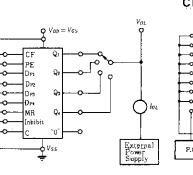
* To calculate total supply current at frequency other than 1kHz.

 $@V_{00} = 5.0V I_{T} = (1.7 \,\mu\text{A/kHz})f + I_{00}, \quad @V_{00} = 10V I_{T} = (3.4 \,\mu\text{A/kHz})f + I_{00}, \quad @V_{00} = 15V I_{T} = (5.1 \,\mu\text{A/kHz})f + I_{00} = 15V I_{T} = 15V I_{T} =$

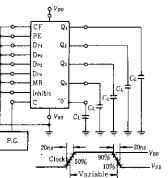
OHITACHI

DC CHARACTERISTIC TEST CIRCUIT





• POWER DISSIPATION TEST CIRCUIT AND WAVEFORM



SWITCHING CHARACTERISTICS $(C_L = 50 \text{ pF}, Ta = 25 \text{°C})$

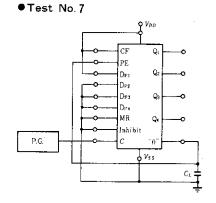
Characteri	stic	Symbol	$V_{DD}(V)$	min	typ	max	Unit
		5.0		180	400	ns	
Output Rise Time	t,	10	_	90	200		
		15	`	65	160		
			5.0	_	100	200	
Output Fall Time	tj	10	_	50	100	ns	
		15	-	37	80		
			5.0	_	550	1100	
	Q Outputs		10		230	450	
Propagation Delay Time		t plH,	15	-	160	340	
i iopagation izeray i fine		t _{PHL}	5.0	_	240	500	ns
	"0" Outputs		10	_	120	300	
			15	—	90	225	1
			5.0	300	100		
Clock Pulse Width		PW_{c}	10	150	50		ns
			15	115	40	_	
			5.0	-	2.0	1.0	MHz
Clock Frequency		PRF	10		5.0	2.5	
			15	_	6.6	3.0	
			5.0			15	μs
Maximum Clock or Inhibit Rise an	nd Fall Time	$t_{\tau_{i}} = t_{f}$	10			15	
	•		15	-	_	15	
			5.0	150	75	-	ns
Hold Time		\$ hold	10	75	25		
			15	60	20		
			5.0	300	100		1
Minimum Preset Enable Pulse W	PWPE	10	150	50		ns	
			15	115	40		
			5.0	350	200	_	
Minimum Master Reset Pulse Wi	dth	PWNR	10	300	100	-	· ns
		15	225	75		1	



SWITCHING TIME TEST CIRCUIT

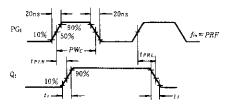
 $\bullet\,\mbox{Test}$ No.1 ~ 6

9 VAD ĊF Q: PE P.G.1 Q₂ Dpt 0 Dra Q3 Ô, Dra Í o Dpa P.G.2 CL MR Q 0 Ci, Inhibit C_L °0" С Ci V_{SS} C_L

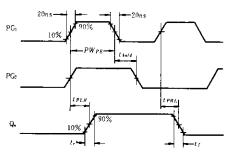


AC TEST METHOD AND SWITCHING WAVEFORMS

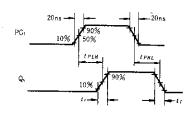
Test No.1



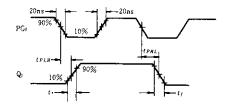
• Test No. 3



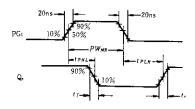
• Test No. 5 & 7



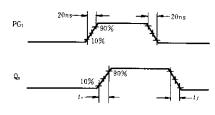
● Test No. 2



• Test No. 4



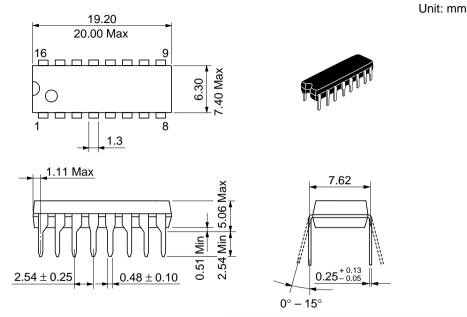




HD14522B, HD14526B----

Characteristic	Test No.	Clock	Inhibit	PE	MR	D _{pn}	CF	Output
	1	PG_1	Vss	Vss	Vss	Vss	Vss	Qi
	2	VDD	PG ₁	Vss	Vss	Vss	Vss	Qı
$t_{I}, t_{I},$	3	Vss	Vss	PG1	Vss	PG ₂	Vss	Q.
ĮplH, įpHl	4	Vss	Vss	VDD	\mathbf{PG}_1	VDD	Vss	Qn
	5	Vss	Vss	VDD	Vss	PG1	Vss	Q.
PWMR	4	Vss	Vss	V _{DD}	PG ₁	VDD	Vss	Q,
PWPE	3	Vss	Vss	PG ₁	Vss	PG2	Vss	Q,
PWc	1	PG1	Vss	Vss	Vs s	Vss	Vss	Qı
PRF	~ 1	PG ₁	Vss	Vss	Vss	Vss	Vss	Qı
troid	3	Vss	Vss	PG ₁	Vss	PG2	Vss	Q,
t., t _j	6	Vss	Vss	Vss	V_{DD}	Vss	PG ₁	"0"
tpln, tphl	7	PG	Vss	See Test Circuit	Vss	See Test Circuit	Voo	"0"





Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

Cautions

- Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.



Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109 NorthAmerica URL http:semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg Europe http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm http://www.hitachi.co.jp/Sicd/indx.htm Japan For further information write to: Hitachi Semiconductor Hitachi Europe GmbH Hitachi Asia Pte. Ltd. (America) Inc. Electronic components Group 16 Collyer Quay #20-00 179 East Tasman Drive, Dornacher Stra§e 3 Hitachi Tower San Jose,CA 95134 D-85622 Feldkirchen, Munich Singapore 049318 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Germany Tel: 535-2100 Tel: <49> (89) 9 9180-0 Fax: 535-1533 Fax: <49> (89) 9 29 30 00

 Fax: <49> (89) 9 29 30 00
 Hita

 Hitachi Europe Ltd.
 Hita

 Electronic Components Group.
 Taip

 Whitebrook Park
 3F,

 Lower Cookham Road
 Tun

 Maidenhead
 Tel:

 Berkshire SL6 8YA, United Kingdom
 Fax

 Tel: <44> (1628) 585000

 Fax: <44> (1628) 778322

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

HITACHI

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

Copyright ' Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.